









SN54HC541, SN74HC541 SCLS305E - JANUARY 1996 - REVISED MAY 2022

# **SNx4HC541 Octal Buffers and Line Drivers With 3-State Outputs**

#### 1 Features

- Wide Operating Voltage Range of 2 V to 6 V
- High-Current 3-State Outputs Drive Bus Lines Directly or Up to 15 LSTTL Loads
- Low Power Consumption, 80-µA Maximum I<sub>CC</sub>
- Typical  $t_{pd} = 10 \text{ ns}$
- ±6-mA Output Drive at 5 V
- Low Input Current of 1 µA Maximum
- Data Flow-Through Pinout (All Inputs on Opposite Side From Outputs)

## 2 Applications

- **LEDs**
- Servers
- PCs and Notebooks
- Wearable Health and Wellness Devices
- Electronic Points of Sale

## 3 Description

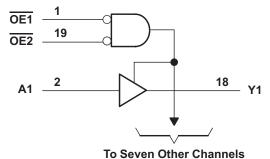
These octal buffers and line drivers feature the performance of the SNx4HC541 devices and a pinout with inputs and outputs on opposite sides of the package. This arrangement greatly facilitates printed circuit board layout.

The 3-state outputs are controlled by a two-input NOR gate. If either output-enable (OE1 or OE2) input is high, all eight outputs are in the high-impedance state. The SNx4HC541 devices provide true data at the outputs.

#### **Device Information**

PART NUMBER	PACKAGE <sup>(1)</sup>	BODY SIZE (NOM)
SN74HC541DW	SOIC (20)	12.80 mm × 7.50 mm
SN74HC541DB	SSOP (20)	7.20 mm × 5.30 mm
SN74HC541N	PDIP (20)	24.33 mm × 6.35 mm
SN74HC541NS	SO (20)	12.60 mm × 5.30 mm
SN74HC541PW	TSSOP (20)	6.50 mm × 4.40 mm
SN54HC541J	CDIP (20)	24.20 mm × 6.92 mm
SN54HC541FK	LCCC (20)	8.89 mm × 8.89 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Copyright © 2016, Texas Instruments Incorporated

**Functional Block Diagram** 

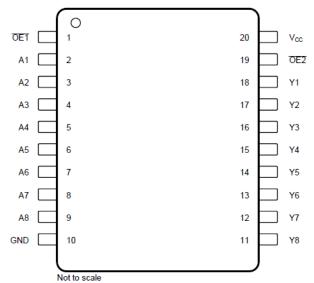


Tab	le of	Contents	
1 Features 2 Applications 3 Description 4 Revision History 5 Pin Configuration and Functions Pin Functions 6 Specifications 6.1 Absolute Maximum Ratings 6.2 ESD Ratings 6.3 Recommended Operating Conditions 6.4 Thermal Information 6.5 Electrical Characteristics, T <sub>A</sub> = 25°C 6.6 Electrical Characteristics, SN54HC541 6.7 Electrical Characteristics, SN74HC541 6.8 Switching Characteristics, C <sub>L</sub> = 50 pF, T <sub>A</sub> = 25°C. 6.9 Switching Characteristics, C <sub>L</sub> = 50 pF, SN54HC541 6.10 Switching Characteristics, C <sub>L</sub> = 50 pF, SN74HC541 6.11 Switching Characteristics, C <sub>L</sub> = 150 pF, SN74HC541 6.12 Switching Characteristics, C <sub>L</sub> = 150 pF, SN54HC541 6.13 Switching Characteristics, C <sub>L</sub> = 150 pF,	11233444555677	6.14 Operating Characteristics. 6.15 Typical Characteristics. 7 Parameter Measurement Information. 8 Detailed Description. 8.1 Overview. 8.2 Functional Block Diagram. 8.3 Feature Description. 8.4 Device Functional Modes. 9 Application and Implementation. 9.1 Application Information. 9.2 Typical Application. 10 Power Supply Recommendations. 11 Layout. 11.1 Layout Guidelines. 11.2 Layout Example. 12 Device and Documentation Support. 12.1 Related Links. 12.2 Receiving Notification of Documentation Up 12.3 Support Resources. 12.4 Trademarks. 12.5 Electrostatic Discharge Caution. 12.6 Glossary. 13 Mechanical, Packaging, and Orderable Information.	
A Revision History NOTE: Page numbers for previous revisions may Changes from Revision D (September 2016) to Updated ESD ratings table to include modern Junction-to-ambient thermal resistance values	differ for the contract of the	sion E (May 2022) ninologysed. DB was 90.2 is now 122.7, DW was 77.5 is	now
109.1, N was 45.2 is now 84.6, NS was 72.8 is  Changes from Revision C (August 2003) to Re		13.4, PW was 98.3 is now 131.8  D (September 2016)	Page

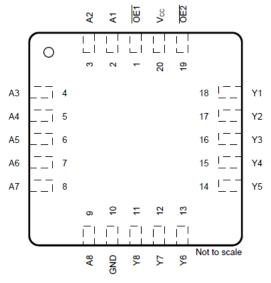
- Added Applications section, Thermal Information table, ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable
- Deleted Ordering Information table, see Mechanical, Packaging, and Orderable Information at the end of the Changed R<sub>θJA</sub> for DB package from 70°C/W: to 90.2°C/W......5
- Changed R<sub>B,IA</sub> for N package from 69°C/W: to 45.2°C/W......5



# **5 Pin Configuration and Functions**



DB, DW, N, NS, J, or PW Package 20-Pin SSOP, SOIC, PDIP, SO, CDIP, or TSSOP Top View



FK Package 20-Pin LCCC Top View

### **Pin Functions**

P	IN	I/O <sup>(1)</sup>	DESCRIPTION
NO.	NAME	1/0**	DESCRIPTION
1	OE1	I	Output enable (active low) Both $\overline{\sf OE}$ must be low to enable outputs
2	A1	I	Channel 1 input
3	A2	I	Channel 2 input
4	A3	I	Channel 3 input
5	A4	I	Channel 4 input
6	A5	I	Channel 5 input
7	A6	I	Channel 6 input
8	A7	I	Channel 7 input
9	A8	I	Channel 8 input
10	GND	_	Ground
11	Y8	0	Channel 8 output
12	Y7	0	Channel 7 output
13	Y6	0	Channel 6 output
14	Y5	0	Channel 5 output
15	Y4	0	Channel 4 output
16	Y3	0	Channel 3 output
17	Y2	0	Channel 2 output
18	Y1	0	Channel 1 output
19	OE2	I	Output enable (active low) both $\overline{\sf OE}$ must be low to enable outputs
20	V <sub>CC</sub>	_	Power pin

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.



## **6 Specifications**

## **6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	$V_I < 0$ or $V_I > V_{CC}$		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±35	mA
	Continuous current through V <sub>CC</sub> or GND			±70	mA
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## 6.2 ESD Ratings

			VALUE	UNIT
\/	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±2000	V
V <sub>(ESD)</sub> Electrostatic discharge	Charged device model (CDM), per ANSI/ESDA/JEDEC JS-002 <sup>(2)</sup>	±1000	v	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- 2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## **6.3 Recommended Operating Conditions**

See note(1)

			MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5	6	V
		V <sub>CC</sub> = 2 V	1.5			
V <sub>IH</sub>	High-level input voltage	V <sub>CC</sub> = 4.5 V	3.15			V
		V <sub>CC</sub> = 6 V	4.2			
		V <sub>CC</sub> = 2 V			0.5	
12	Low-level input voltage	V <sub>CC</sub> = 4.5 V			1.35	V
		V <sub>CC</sub> = 6 V			1.8	
VI	Input voltage		0		V <sub>CC</sub>	V
Vo	Output voltage		0		V <sub>CC</sub>	V
		V <sub>CC</sub> = 2 V			1000	
Δt/Δν	Input transition rise and fall time	$V_{CC} = 4.5 \text{ V}$			500	ns
		V <sub>CC</sub> = 6 V			400	
_	Operating free-air temperature	SN54HC541	-55		125	°C
T <sub>A</sub>		SN74HC541	-40		85	C

All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. See *Implications of Slow or Floating CMOS Inputs*, SCBA004.



## **6.4 Thermal Information**

				SN74HC541			
		DB (SSOP)	DW (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)	
THERMAL METRIC		20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance <sup>(1)</sup>	122.7	109.1	84.6	113.4	131.8	°C/W
R <sub>θJC (top)</sub>	Junction-to-case (top) thermal resistance	81.6	76	72.5	78.6	72.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	77.5	77.6	65.3	78.4	82.8	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	46.1	51.5	55.3	47.1	21.5	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	77.1	77.1	65.2	78.1	82.4	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

# 6.5 Electrical Characteristics, $T_A = 25$ °C

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CO	ONDITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
			2 V	1.9	1.998	8 9 9 9 3 8 0.1 0.1 0.1 0.26 0.26 ±100 ±0.5 8	
	$V_{I} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -20 \ \mu\text{A}$ $I_{OH} = -20 \ \mu\text{A}$ $I_{OH} = -6 \ \text{mA}$ $I_{OH} = -6 \ \text{mA}$ $I_{OH} = -7.8 \ \text{mA}$ $I_{OH} = -7.8 \ \text{mA}$ $I_{OL} = 20 \ \mu\text{A}$ $I_{OL} = 20 \ \mu\text{A}$ $I_{OL} = 20 \ \mu\text{A}$ $I_{OL} = 6 \ \text{mA}$ $I_{OL} = 6 \ \text{mA}$ $I_{OL} = 6 \ \text{mA}$ $I_{OL} = 7.8 \ \text{mA}$ $I_{OL} = 7.8 \ \text{mA}$ $I_{OL} = 7.8 \ \text{mA}$ $I_{OL} = 10 \ \text{mA}$ $I_{O$						
V <sub>OH</sub>			6 V	5.9	5.999		V
$V_{OL} \qquad \qquad V_{I} = V_{IH} \text{ or } V_{IL}$ $I_{I} \qquad \qquad V_{I} = V_{CC} \text{ or } 0$	I <sub>OH</sub> = -6 mA	4.5 V	3.98	4.3			
		$I_{OH} = -7.8 \text{ mA}$	6 V	5.48	5.8	0.1 0.1 0.1 0.26 0.26 ±100 ±0.5	
	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>		2 V	0.002		0.1	
		I <sub>OL</sub> = 20 μA	4.5 V	0.001		0.1	
V <sub>OL</sub>			6 V	0.001		0.1	V
		I <sub>OL</sub> = 6 mA	4.5 V	0.17		0.26	
		I <sub>OL</sub> = 7.8 mA	6 V	0.15		98 99 99 4.3 5.8 0.1 0.1 0.1 0.26 0.26 ±100 ±0.5	
I <sub>I</sub>	V <sub>I</sub> = V <sub>CC</sub> or 0		6 V	±0.1		±100	nA
I <sub>OZ</sub>	$V_O = V_{CC}$ or 0		6 V	±0.01		±0.5	μA
Icc	$V_I = V_{CC}$ or 0, $I_O = 0$		6 V			8	μA
Ci			2 V to 6 V		3	10	pF

## 6.6 Electrical Characteristics, SN54HC541

over operating free-air temperature range (unless otherwise noted)

PARAME1	ΓER	TEST CON	DITIONS	V <sub>cc</sub>	MIN	TYP	MAX	UNIT
				2 V	1.9			
		I <sub>OH</sub> = –20 μA	4.5 V	4.4				
V <sub>OH</sub>		$V_I = V_{IH}$ or $V_{IL}$		6 V	5.9			V
			I <sub>OH</sub> = -6 mA	4.5 V	3.7			
			I <sub>OH</sub> = -7.8 mA	6 V	5.2			

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONI	DITIONS	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
	$V_{I} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 20  \mu A$ $I_{OL} = 6  mA$ $I_{OL} = 6  mA$ $I_{OL} = 7.8  mA$ $V_{I} = V_{CC} \text{ or } 0$ $V_{O} = V_{CC} \text{ or } 0$ $V_{I} = V_{CC} \text{ or } 0$						
		0.1					
V <sub>OL</sub>	$V_I = V_{IH}$ or $V_{IL}$		6 V		0.1 0.1 0.4 0.4 ±1000 ±10	V	
	I <sub>OL</sub> = 6 mA 4.5 V 0.4	0.4					
		I <sub>OL</sub> = 7.8 mA	6 V			0.1 0.1 0.4 0.4 ±1000 n ±10 µ	
I <sub>I</sub>	V <sub>I</sub> = V <sub>CC</sub> or 0		6 V			±1000	nA
I <sub>OZ</sub>	$V_O = V_{CC}$ or 0		6 V			±10	μA
I <sub>CC</sub>	$V_I = V_{CC}$ or 0, $I_O = 0$		6 V			160	μA
C <sub>i</sub>			2 V to 6 V			10	pF

# 6.7 Electrical Characteristics, SN74HC541

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST	CONDITIONS	V <sub>cc</sub>	MIN	TYP	MAX	UNIT
			2 V	1.9			
		$I_{OH} = -20 \mu A$	2 V 1.9 4.5 V 4.4 6 V 5.9 4.5 V 3.84 6 V 5.34 2 V 0.1 4.5 V 0.1 6 V 0.1 4.5 V 0.33 6 V 0.33 6 V ±1000 6 V ±5 6 V 80				
$V_{OH}$	$V_I = V_{IH}$ or $V_{IL}$		6 V	5.9	1.9 4.4 5.9 3.84 5.34 0.1 0.1 0.1 0.33 0.33 ±1000 ±5 80	V	
		I <sub>OH</sub> = -6 mA	4.5 V	3.84			
		$I_{OH} = -7.8 \text{ mA}$	6 V	5.34			
$V_{OL}$ $V_{I} = V_{IH} \text{ or } V_{IL}$		2 V			0.1		
		$I_{OL} = 20 \mu A$	4.5 V			0.1	
		6 V			0.1	V	
		I <sub>OL</sub> = 6 mA	4.5 V			0.33	
		I <sub>OL</sub> = 7.8 mA	6 V			0.33	
I <sub>I</sub>	V <sub>I</sub> = V <sub>CC</sub> or 0		6 V			±1000	nA
I <sub>OZ</sub>	$V_O = V_{CC}$ or 0		6 V			±5	μΑ
I <sub>CC</sub>	$V_I = V_{CC}$ or 0, $I_O = 0$		6 V			80	μΑ
C <sub>i</sub>			2 V to 6 V			10	pF

# 6.8 Switching Characteristics, $C_L = 50$ pF, $T_A = 25$ °C

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 7-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub>	MIN	TYP	MAX	UNIT
			2 V		40	115	
t <sub>pd</sub>	A	Υ	4.5 V		12	23	ns
			6 V		10	20	
			2 V		80	150	
t <sub>en</sub>	ŌĒ	Υ	4.5 V		17	30	ns
		6 V		15	26		
			2 V		40	150	
t <sub>dis</sub>	ŌĒ	Υ	4.5 V		18	30	ns
			6 V		17	26	
			2 V		28	60	
t <sub>t</sub>		Υ	4.5 V		8	12	ns
			6 V		6	10	



# 6.9 Switching Characteristics, $C_L$ = 50 pF, SN54HC541

over recommended operating free-air temperature range, C<sub>L</sub> = 50 pF (unless otherwise noted) (see Figure 7-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub>	MIN TYP MAX	UNIT	
			2 V	171		
$t_{pd}$	A	Υ	4.5 V	34	ns	
			6 V	29		
			2 V	224		
t <sub>en</sub>	ŌĒ	Y	4.5 V	45	ns	
			6 V	38		
			2 V	224		
t <sub>dis</sub>	ŌĒ	Y	4.5 V	45	ns	
			6 V	38	]	
			2 V	90	1 1	
lt <sub>t</sub>		Y	4.5 V	18		
			6 V	15	1	

# 6.10 Switching Characteristics, $C_L = 50$ pF, SN74HC541

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 7-1)

PARAMETER	FROM (INPUT)	TO (OUTPUT) V <sub>CC</sub>		MIN TYP MAX	UNIT	
			2 V	144		
t <sub>pd</sub>	A	Υ	4.5 V	29	ns	
			6 V	25		
			2 V	188		
t <sub>en</sub>	ŌĒ	Y	4.5 V	38	ns	
			6 V	32		
		Y	2 V	188	1	
t <sub>dis</sub>	ŌĒ		4.5 V	38		
			6 V	32		
			2 V	75		
t <sub>t</sub>		Y	4.5 V	15	ns	
			6 V	13		

# 6.11 Switching Characteristics, $C_L = 150 \text{ pF}$ , $T_A = 25^{\circ}\text{C}$

over recommended operating free-air temperature range, C<sub>L</sub> = 150 pF (unless otherwise noted) (see Figure 7-1)

ever recentimenada eper		(			• /		
PARAMETER	PARAMETER FROM (INPUT)		V <sub>cc</sub>	MIN TYP I		MAX	UNIT
			2 V		65	165	
t <sub>pd</sub>	Α	Υ	4.5 V		16	33	ns
			6 V		14	28	
	ŌE	Y	2 V		100	200	
t <sub>en</sub>			4.5 V		20	40	ns
			6 V		17	34	
			2 V		45	210	
t <sub>t</sub>		Υ	4.5 V		17	42	ns
			6 V		13	36	



# 6.12 Switching Characteristics, C<sub>L</sub> = 150 pF, SN54HC541

over recommended operating free-air temperature range, C<sub>L</sub> = 150 pF (unless otherwise noted) (see Figure 7-1)

PARAMETER	RAMETER FROM (INPUT)		V <sub>CC</sub>	MIN TYP MAX	UNIT
			2 V	246	
t <sub>pd</sub>	A	Υ	4.5 V	49	ns
			6 V	42	
	ŌĒ	Y	2 V	298	
t <sub>en</sub>			4.5 V	60	ns
			6 V	51	
			2 V	315	
t <sub>t</sub>		Υ	4.5 V	63	ns
			6 V	53	

# 6.13 Switching Characteristics, $C_L = 150 pF$ , SN74HC541

over recommended operating free-air temperature range, C<sub>L</sub> = 150 pF (unless otherwise noted) (see Figure 7-1)

PARAMETER	PARAMETER FROM (INPUT)		V <sub>CC</sub>	MIN TYP MAX	UNIT
			2 V	206	
t <sub>pd</sub>	A	Υ	4.5 V	41	ns
			6 V	35	
		Y	2 V	250	
t <sub>en</sub>	ŌĒ		4.5 V	50	ns
			6 V	43	
			2 V	265	
t <sub>t</sub>		Y	4.5 V	53	ns
			6 V	45	

# **6.14 Operating Characteristics**

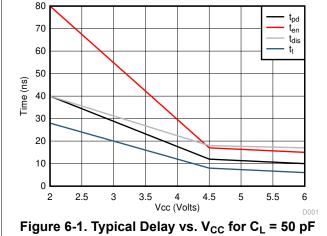
 $T_A = 25^{\circ}C$ 

· A = 0	· A = 0									
	PARAMETER	TEST CONDITIONS	TYP	UNIT						
Cpd	Power dissipation capacitance per buffer/driver	No load	35	pF						

Submit Document Feedback



# **6.15 Typical Characteristics**



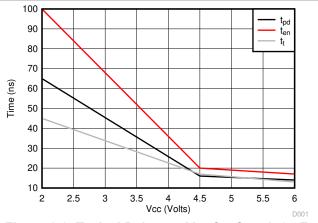
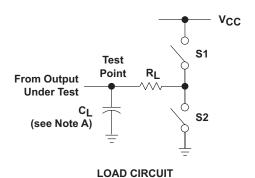
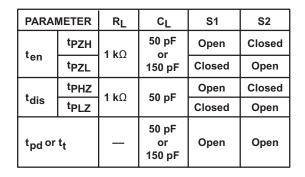


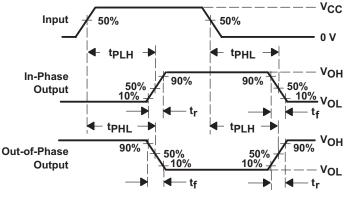
Figure 6-2. Typical Delay vs.  $V_{CC}$  for  $C_L$  = 150 pF



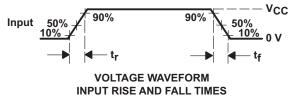
## 7 Parameter Measurement Information

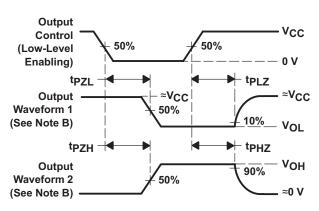






VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT TRANSITION TIMES





VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

- A. C<sub>L</sub> includes probe and test-fixture capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_f = 6$  ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

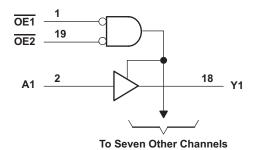
Figure 7-1. Load Circuit and Voltage Waveforms

## **8 Detailed Description**

## 8.1 Overview

The SN74HC541 device has 8 inputs and outputs where data from the A inputs go to the Y outputs. The output enables of the device control whether the information from the A inputs go to the Y outputs. These enable pins cause the device to go into high Z if either  $\overline{OE1}$  or  $\overline{OE2}$  are high. The  $\overline{OE}$ s should be tied to  $V_{CC}$  through a pull up resistor to ensure the high impedance state during power up or power down; the minimum value of the resistor is determined by the current sinking capability of the driver.

## 8.2 Functional Block Diagram



Copyright © 2016, Texas Instruments Incorporated

Figure 8-1. Logic Diagram (Positive Logic)

## 8.3 Feature Description

The SNx4HC541 has a wide operating voltage range of 2 V to 6 V. The device has multiple enable pins, and the device pinout enables simple board layout with outputs across from inputs.

## 8.4 Device Functional Modes

Table 8-1 lists the functional modes of the SNx4HC541.

Table 8-1. Function Table (Each Buffer/Driver)

	INPUTS	OUTPUT	
OE1	OE2	Y	
L	L	L	L
L	L	Н	Н
Н	X	X	Hi-Z
Х	Н	X	Hi-Z



## 9 Application and Implementation

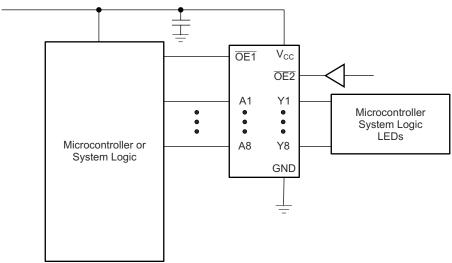
#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

## 9.1 Application Information

SN74HC541 is a wide range CMOS device that can be used over large voltage ranges. The device can be used anywhere from 2 to 6 Volts. The device can drive up to 6 mA of current at 5 Volts. This makes it perfect for driving bus lines directly or up to 15 LSTTL Loads. It can be used to drive anything from micro controllers and system logic devices to LEDs.

## 9.2 Typical Application



Copyright © 2016, Texas Instruments Incorporated

Figure 9-1. Typical Application Diagram

## 9.2.1 Design Requirements

This device uses CMOS technology and has a wide voltage range. Take care to avoid pulling too much current from the outputs as to not exceed 6 mA. Also, take care to not go over  $V_{CC}$  voltage to avoid damage to the device.

### 9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions
  - Rise time and fall time specs: See (Δt/ΔV) in the Section 6.3 table.
  - Specified high and low levels: See (VIH and VIL) in the Section 6.3 table.
  - Inputs should not be pulled above V<sub>CC</sub>.
- 2. Recommended Output Conditions
  - Load currents should not exceed 6 mA for the part
  - Outputs should not be pulled above V<sub>CC</sub>.



## 9.2.3 Application Curve

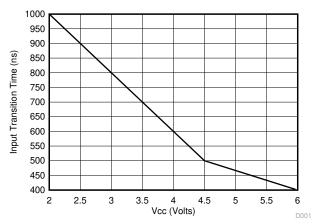


Figure 9-2. Input Transition Time vs. V<sub>CC</sub>



## 10 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the Section 6.3 table.

Each  $V_{CC}$  pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1- $\mu$ F is recommended; if there are multiple  $V_{CC}$  pins, then 0.01- $\mu$ F or 0.022- $\mu$ F is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1- $\mu$ F and a 1- $\mu$ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

## 11 Layout

## 11.1 Layout Guidelines

When using multiple bit logic devices inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. The Section 6.3 section specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$  whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it disables the output section of the part when asserted. This does not disable the input section of the I/Os, so they cannot float when disabled.

## 11.2 Layout Example

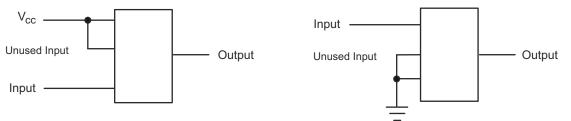


Figure 11-1. Layout Diagram

# 12 Device and Documentation Support

#### 12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 12-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN54HC541	N54HC541 Click here		Click here	Click here	Click here	
SN74HC541	Click here	Click here	Click here	Click here	Click here	

## 12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 12.3 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 12.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

#### 12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 12.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com

7-Oct-2025

## **PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	<b>RoHS</b> (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
JM38510/65711BRA	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65711BRA
JM38510/65711BRA.A	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65711BRA
M38510/65711BRA	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65711BRA
SN54HC541J	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC541J
SN54HC541J.A	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SN54HC541J
SN74HC541DBR	Active	Production	SSOP (DB)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC541
SN74HC541DBR.A	Active	Production	SSOP (DB)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC541
SN74HC541DW	Obsolete	Production	SOIC (DW)   20	-	-	Call TI	Call TI	-40 to 85	HC541
SN74HC541DWR	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC541
SN74HC541DWR.A	Active	Production	SOIC (DW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC541
SN74HC541N	Active	Production	PDIP (N)   20	20   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC541N
SN74HC541N.A	Active	Production	PDIP (N)   20	20   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC541N
SN74HC541N.B	Active	Production	PDIP (N)   20	20   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC541N
SN74HC541NE4	Active	Production	PDIP (N)   20	20   TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HC541N
SN74HC541NSR	Active	Production	SOP (NS)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC541
SN74HC541NSR.A	Active	Production	SOP (NS)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC541
SN74HC541PW	Obsolete	Production	TSSOP (PW)   20	-	-	Call TI	Call TI	-40 to 85	HC541
SN74HC541PWR	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC541
SN74HC541PWR.A	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC541
SN74HC541PWR.B	Active	Production	TSSOP (PW)   20	2000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC541
SN74HC541PWT	Obsolete	Production	TSSOP (PW)   20	-	-	Call TI	Call TI	-40 to 85	HC541
SNJ54HC541FK	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HC 541FK
SNJ54HC541FK.A	Active	Production	LCCC (FK)   20	55   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HC 541FK
SNJ54HC541J	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HC541J
SNJ54HC541J.A	Active	Production	CDIP (J)   20	20   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	SNJ54HC541J

7-Oct-2025

www.ti.com

- (1) Status: For more details on status, see our product life cycle.
- (2) Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN54HC541, SN74HC541:

Catalog: SN74HC541

Military: SN54HC541

NOTE: Qualified Version Definitions:

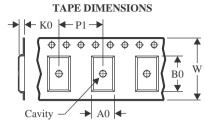
- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 25-Jul-2025

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC541DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74HC541DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74HC541NSR	SOP	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74HC541PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1

www.ti.com 25-Jul-2025



#### \*All dimensions are nominal

	7 till dillitorioriorio di o riorimidi							
	Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
	SN74HC541DBR	SSOP	DB	20	2000	353.0	353.0	32.0
	SN74HC541DWR	SOIC	DW	20	2000	356.0	356.0	45.0
	SN74HC541NSR	SOP	NS	20	2000	356.0	356.0	45.0
١	SN74HC541PWR	TSSOP	PW	20	2000	353.0	353.0	32.0

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 25-Jul-2025

## **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74HC541N	N	PDIP	20	20	506	13.97	11230	4.32
SN74HC541N.A	N	PDIP	20	20	506	13.97	11230	4.32
SN74HC541N.B	N	PDIP	20	20	506	13.97	11230	4.32
SN74HC541NE4	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54HC541FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54HC541FK.A	FK	LCCC	20	55	506.98	12.06	2030	NA





#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.







#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



### 14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



**INSTRUMENTS** www.ti.com

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



#### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025. Texas Instruments Incorporated